

SM05T1G Series

ESD Protection Diode Array

Dual Common Anode

These dual monolithic silicon surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features:

- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Working Peak Reverse Voltage Range – 5.0 V to 36 V
- Peak Power – 300 Watt (8/20 μ s)
- Low Leakage – 1.0 μ A
- Flammability Rating UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

Mechanical Characteristics:

CASE: Void-Free, Transfer-Molded, Thermosetting Plastic Case

FINISH: Corrosion Resistant Finish, Easily Solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

Package Designed for Optimal Automated Board Assembly

Small Package Size for High Density Applications

Available in 8 mm Tape and Reel

Use the Device Number to Order the 7 Inch/3,000 Unit Reel

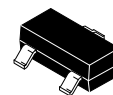
Replace the “T1” with “T3” in the Device Number to Order the

13 Inch/10,000 Unit Reel

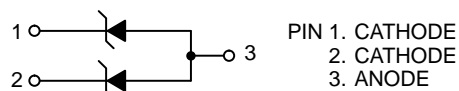


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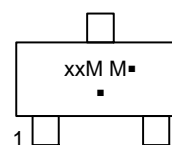
www.onsemi.com



SOT-23
CASE 318
STYLE 12



MARKING DIAGRAM



xxM = Device Code
xx = 05, 12, 15, 24, 36
M = Date Code*
■ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------|---------------------|-------------------|
| SM05T1G | SOT-23 (Pb-Free) | 3,000/Tape & Reel |
| SZSM05T1G | SOT-23 (Pb-Free) | 3,000/Tape & Reel |
| SM12T1G | SOT-23 (Pb-Free) | 3,000/Tape & Reel |
| SM15T1G | SOT-23 (Pb-Free) | 3,000/Tape & Reel |
| SM24T1G | SOT-23 (Pb-Free) | 3,000/Tape & Reel |
| SM36T1G | SOT-23 (Pb-Free) | 3,000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------|----------------------|---|
| Peak Power Dissipation @ 20 μ s (Note 1) @ $T_L \leq 25^\circ\text{C}$ | P_{pk} | 300 | W |
| IEC 61000-4-2 (ESD) Air Contact | | ± 15 ± 26 | kV |
| IEC 61000-4-4 (EFT) | | 40 | A |
| IEC 61000-4-5 (Lightning) | | 12 | A |
| Total Power Dissipation on FR-5 Board (Note 2) @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 225 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 1.8 556 | $\text{mW}/^\circ\text{C}$ $^\circ\text{C}/\text{W}$ |
| Total Power Dissipation on Alumina Substrate (Note 3) @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 300 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 2.4 417 | $\text{mW}/^\circ\text{C}$ $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | T_J, T_{stg} | - 55 to +150 | $^\circ\text{C}$ |
| Lead Solder Temperature - Maximum (10 Second Duration) | T_L | 260 | $^\circ\text{C}$ |

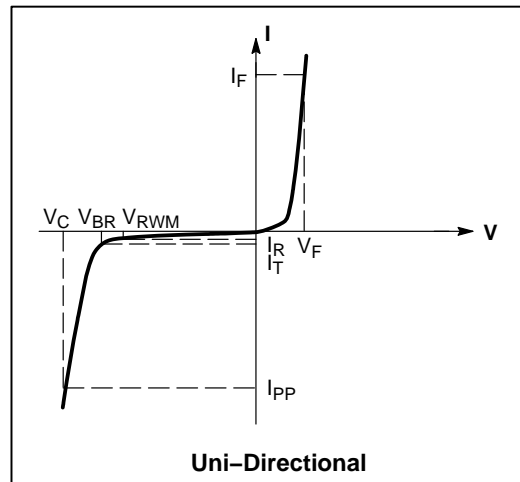
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 3
 2. FR-5 = 1.0 x 0.75 x 0.62 in.
 3. Alumina = 0.4 x 0.3 x 0.024 in., 99.5% alumina
- NOTE: Other voltages may be available upon request

ELECTRICAL CHARACTERISTICS

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

| Symbol | Parameter |
|-----------------|---|
| I_{PP} | Maximum Reverse Peak Pulse Current |
| V_C | Clamping Voltage @ I_{PP} |
| V_{RWM} | Working Peak Reverse Voltage |
| I_R | Maximum Reverse Leakage Current @ V_{RWM} |
| V_{BR} | Breakdown Voltage @ I_T |
| I_T | Test Current |
| ΘV_{BR} | Maximum Temperature Coefficient of V_{BR} |
| I_F | Forward Current |
| V_F | Forward Voltage @ I_F |
| Z_{ZT} | Maximum Zener Impedance @ I_{ZT} |
| I_{ZK} | Reverse Current |
| Z_{ZK} | Maximum Zener Impedance @ I_{ZK} |



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Device* | Device Marking | V_{RWM} (Volts) | I_R @ V_{RWM} (μA) | V_{BR} , Breakdown Voltage | | I_T (mA) | V_C @ $I_{PP} = 1$ Amp (Volts) | Max I_{PP} (Note 4) (Amps) | Typical Capacitance |
|---------|----------------|----------------------|--|------------------------------|-------|---------------|--|------------------------------------|---------------------------------|
| | | | | (Volts) | | | | | Pin 1 to 3 @ 0 Volts (pF) |
| | | | | Min | Max | | | | |
| SM05T1G | 05M | 5 | 10 | 6.2 | 7.3 | 1.0 | 9.8 | 17 | 225 |
| SM12T1G | 12M | 12 | 1.0 | 13.3 | 15.75 | 1.0 | 19 | 12 | 95 |
| SM15T1G | 15M | 15 | 1.0 | 16.7 | 19.6 | 1.0 | 24 | 10 | 100 |
| SM24T1G | 24M | 24 | 1.0 | 26.7 | 31.35 | 1.0 | 43 | 5.0 | 60 |
| SM36T1G | 36M | 36 | 1.0 | 40.0 | 46.95 | 1.0 | 60 | 4.0 | 45 |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. 8/20 μ s pulse waveform per Figure 3

*Include SZ-prefix devices where applicable.

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TYPICAL CHARACTERISTICS

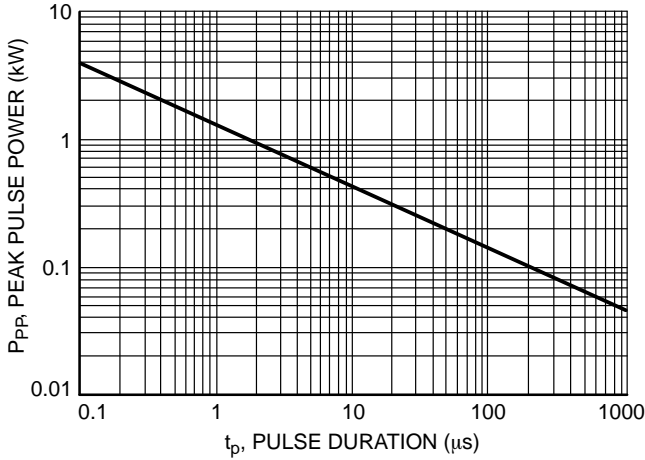


Figure 1. Non-Repetitive Peak Pulse Power versus Pulse Time

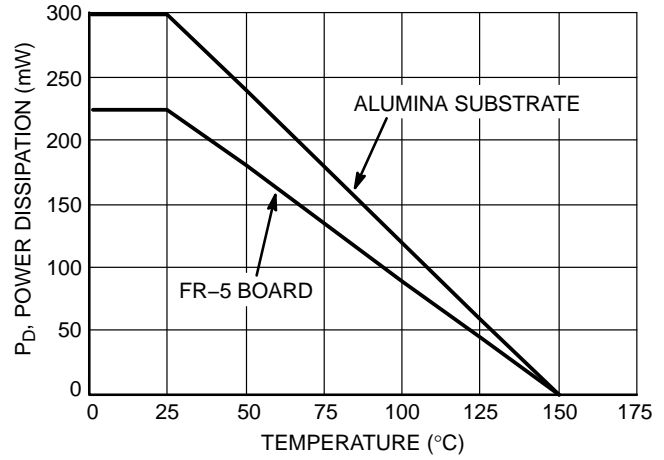


Figure 2. Steady State Power Derating Curve

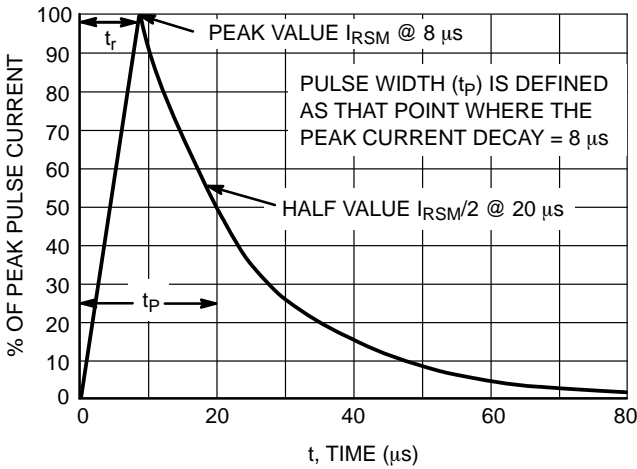


Figure 3. 8/20 μ s Pulse Waveform

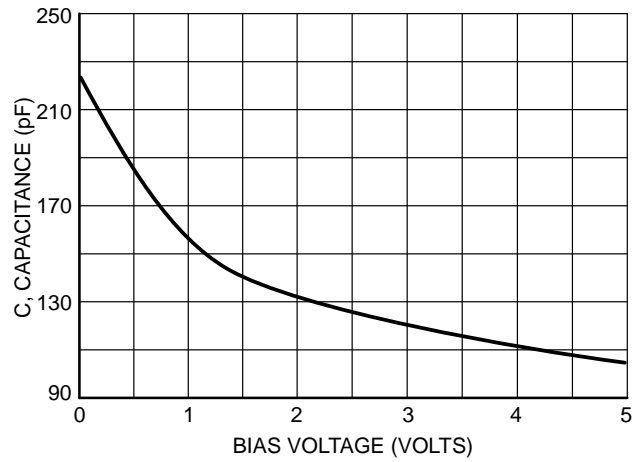


Figure 4. Typical Diode Capacitance (SM05)

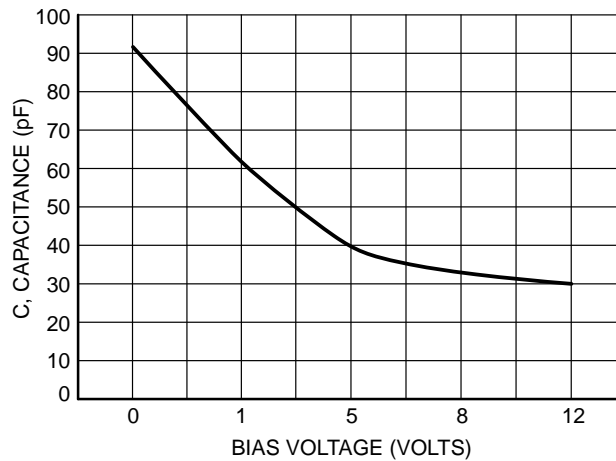


Figure 5. Typical Diode Capacitance (SM12)

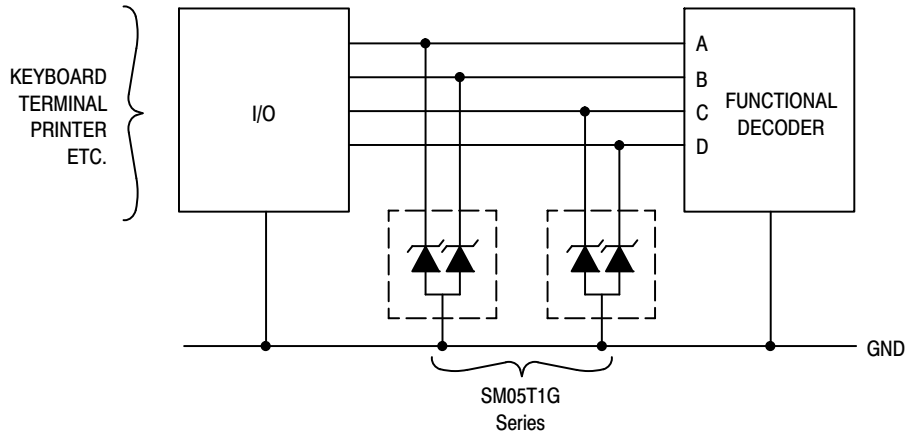
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TYPICAL COMMON ANODE APPLICATIONS

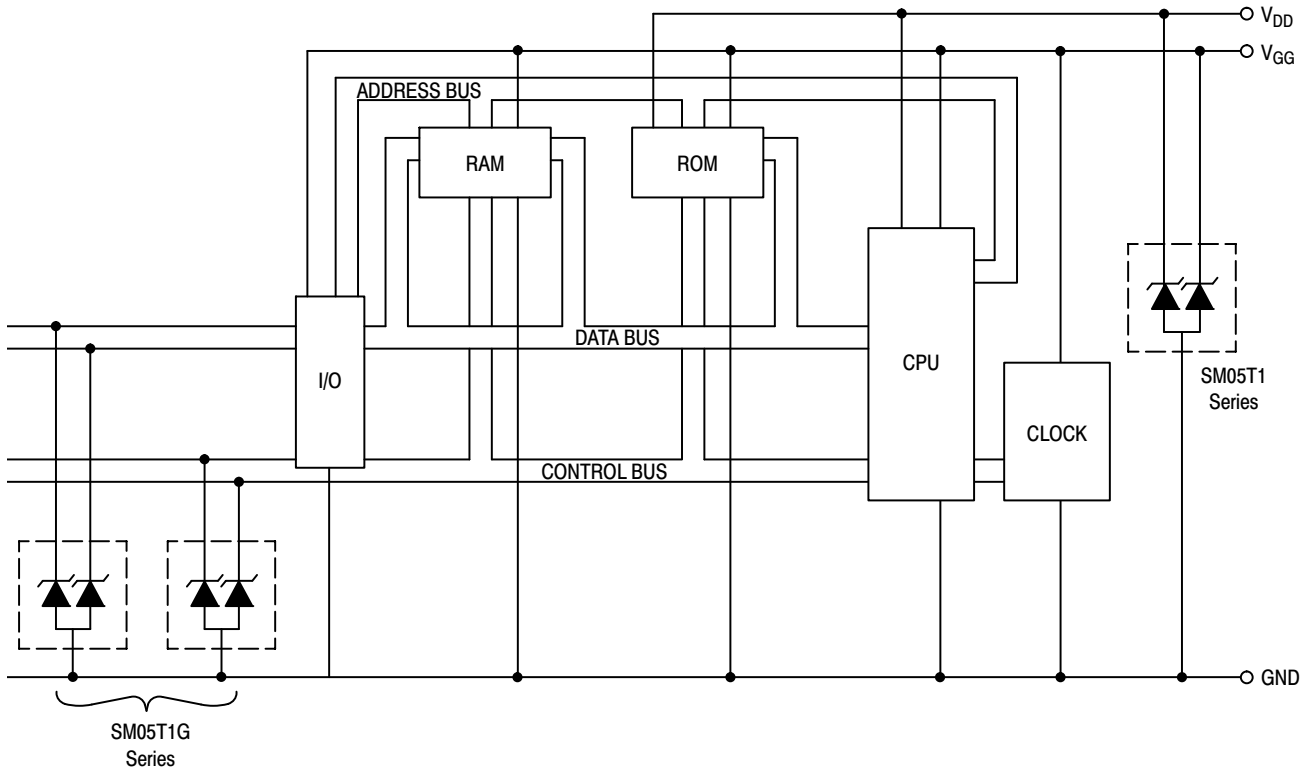
A quad junction common anode design in a SOT-23 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. Two simplified examples of surge protection applications are illustrated below.

Computer Interface Protection



Microprocessor Protection



MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

ON Semiconductor®



SOT-23 (TO-236) CASE 318-08 ISSUE AS

DATE 30 JAN 2018

SCALE 4:1



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| c | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| T | 0° | --- | 10° | 0° | --- | 10° |

RECOMMENDED SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present.

STYLE 1 THRU 5:
CANCELLED

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 7:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 8:
PIN 1. ANODE
2. NO CONNECTION
3. CATHODE

STYLE 9:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 10:
PIN 1. DRAIN
2. SOURCE
3. GATE

STYLE 11:
PIN 1. ANODE
2. CATHODE
3. CATHODE-ANODE

STYLE 12:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 13:
PIN 1. SOURCE
2. DRAIN
3. GATE

STYLE 14:
PIN 1. CATHODE
2. GATE
3. ANODE

STYLE 15:
PIN 1. GATE
2. CATHODE
3. ANODE

STYLE 16:
PIN 1. ANODE
2. CATHODE
3. CATHODE

STYLE 17:
PIN 1. NO CONNECTION
2. ANODE
3. CATHODE

STYLE 18:
PIN 1. NO CONNECTION
2. CATHODE
3. ANODE

STYLE 19:
PIN 1. CATHODE
2. ANODE
3. CATHODE-ANODE

STYLE 20:
PIN 1. CATHODE
2. ANODE
3. GATE

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 22:
PIN 1. RETURN
2. OUTPUT
3. INPUT

STYLE 23:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 24:
PIN 1. GATE
2. DRAIN
3. SOURCE

STYLE 25:
PIN 1. ANODE
2. CATHODE
3. GATE

STYLE 26:
PIN 1. CATHODE
2. ANODE
3. NO CONNECTION

STYLE 27:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

STYLE 28:
PIN 1. ANODE
2. ANODE
3. ANODE

| | | |
|-------------------------|------------------------|--|
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| DESCRIPTION: | SOT-23 (TO-236) | PAGE 1 OF 1 |

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